NSN 5961-01-332-9507

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-9507 **Inclosure Material:** Plastic **Overall Length:** Between 0.690 inches and 0.770 inches **Terminal Length:** Between 0.125 inches and 0.175 inches **Overall Height:** Between 0.105 inches and 0.175 inches **Overall Width:** Between 0.280 inches and 0.310 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -100.0 drain to source voltage all transistor and -100.0 drain to gate voltage all transistor **Current Rating Per Characteristic:** -3.00 amperes drain current all transistor **Power Rating Per Characteristic:** 1.4 watts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: